

Abstracts

An Ultra Broadband GaAs MESFET Preamplifier IC for a 10Gb/s Optical Communication System (1992 [MCS])

M. Miyashita, K. Maemura, K. Yamamoto, T. Shimura, M. Nogami, K. Motoshima, T. Kitayama and Y. Mitsui. "An Ultra Broadband GaAs MESFET Preamplifier IC for a 10Gb/s Optical Communication System (1992 [MCS])." 1992 Microwave and Millimeter-Wave Monolithic Circuits Symposium Digest 92.1 (1992 [MCS]): 127-130.

An ultra broadband GaAs MESFET preamplifier IC is developed for a 10 Gb/s optical communication system. High transimpedance of 44 dB Omega has been obtained for DC to 12 GHz. A receiver has also been fabricated by using this preamplifier IC and a photodiode. The receiver operates with extremely low equivalent input noise current of 12.6 pA/spl radic/Hz for DC to 7.8 GHz. This paper describes circuit design, high frequency characteristics of the preamplifier IC and the receiver.

[Return to main document.](#)